# **Differential LVECL/ECL to LVTTL Translator**

The MC100EPT25 is a Differential LVECL/ECL to LVTTL translator. This device requires +3.3V, -3.3V to -5.2V, and ground. The small outline 8-lead SOIC package and the single gate of the EPT25 make it ideal for applications which require the translation of a clock or data signal.

The VBB output allows the EPT25 to also be used in a single–ended input mode. In this mode the VBB output is tied to the D input for a non–inverting buffer or the  $\overline{D}$  input for an inverting buffer. If used, the VBB pin should be bypassed to ground via a 0.01 mF capacitator.

- 1.1ns Typical Propagation Delay
- 275MHz Fmax (Clock bit stream, not pseudo-random)
- Differential LVECL/ECL inputs
- Small Outline SOIC Package
- 24mA TTL outputs
- Flow Through Pinouts
- Internal Input Resistors: Pulldown on D, Pulldown and Pullup on D
- Q Output will default LOW with inputs open or at GND
- ESD Protection: >4000V HBM, >200V MM
- V<sub>BB</sub> Output
- New Differential Input Common Mode Range
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack.
   For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 111 devices

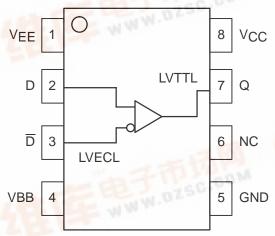


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram



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MARKING DIAGRAMS\*



SO-8 D SUFFIX CASE 751





TSSOP-8 DT SUFFIX CASE 948R



A = Assembly Location

L = Wafer Lot

Y = Year

W = Work Week

\*For additional information, see Application Note AND8002/D

PIN DESCRIPTION						
PIN	FUNCTION					
Q	LVTTL Output					
D, $\overline{D}$	Differential LVECL Input Pair					
Vcc	Positive Supply					
V <sub>BB</sub>	Output Reference Voltage					
GND	Ground					
VEE	Negative Supply					

#### **ORDERING INFORMATION**

Device	Package	Shipping
MC100EPT25D	SO-8	98 Units / Rail
MC100EPT25DR2	SO-8	2500 / Reel
MC100EPT25DT	TSSOP-8	98 Units / Rail
MC100EPT25DTR2	TSSOP-8	2500 / Reel



#### **MAXIMUM RATINGS\***

Symbol	Parameter	Value	Unit	
VCC	Power Supply (Referenced to GND, V <sub>EE</sub> = -3.3V)	0 to 3.8	VDC	
VEE	Power Supply (Referenced to GND, V <sub>CC</sub> = +3.3V)	-6.0 to 0	VDC	
VI	Input Voltage (V <sub>I</sub> not more positive than GND)		0 to 3.8	VDC
l <sub>out</sub>	Output Current	Continuous Surge	50 100	mA
I <sub>BB</sub>	V <sub>BB</sub> Sink/Source Current†		± 0.5	mA
TA	Operating Temperature Range		-40 to +85	°C
T <sub>stg</sub>	Storage Temperature		-65 to +150	°C
θЈА	Thermal Resistance (Junction–to–Ambient)	Still Air 500lfpm	190 130	°C/W
θJC	Thermal Resistance (Junction-to-Case)		41 to 44 ± 5%	°C/W
T <sub>sol</sub>	Solder Temperature (<2 to 3 Seconds: 245°C desire	ed)	265	°C

<sup>\*</sup> Maximum Ratings are those values beyond which damage to the device may occur.

#### DC CHARACTERISTICS, ECL/LVECL ( $V_{CC} = +3.3V$ ; $V_{EE} = -5.5V$ to -3.0V, GND = 0V)

			–40°C		25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
IEE	Power Supply Current (Note 1.)	8.0	16	25	8.0	16	25	8.0	16	25	mA
VIH	Input HIGH Voltage Single Ended (Note 4.)	-1165		-880	-1165		-880	-1165		-880	mV
VIL	Input LOW Voltage Single Ended (Note 4.)	-1810		-1625	-1810		-1625	-1810		-1625	mV
V <sub>BB</sub>	Output Voltage Reference	-1550	-1450	-1350	-1550	-1450	-1350	-1550	-1450	-1350	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Note 3.)	VEE	+2.0	0.0	VEE	+2.0	0.0	VEE	+2.0	0.0	V
lіН	Input HIGH Current			150			150			150	μΑ
IIL	Input LOW Current DDD	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: 100EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

1. (V<sub>CC</sub> = +3.3V, GND = 0V, V<sub>EE</sub> = -3.3V), all other pins floating.

2. All loading with 500 ohms to GND, C<sub>L</sub> = 20pF.

3. V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, max varies 1:1 with V<sub>CC</sub>.

4. Input and output parameters vary 1:1 with V<sub>CC</sub>.

<sup>†</sup> Use for inputs of same package only.

### TTL OUTPUT DC CHARACTERISTICS (VCC = $3.3V \pm 0.3V$ ; GND = 0V; VEE = $-3.3V \pm 0.3V$ ; TA = $-40^{\circ}$ C to $85^{\circ}$ C)

Symbol	Characteristic			Max	Unit
<sup>I</sup> CCH	Power Supply Current (Outputs set to HIGH)	6.0	10	14	mA
ICCL	Power Supply Current (Outputs set to LOW)		12	17	mA
Vон	Output HIGH Voltage (I <sub>OH</sub> = -3.0mA) (Note 5.)				V
VOL	Output LOW Voltage (I <sub>OL</sub> = 24mA) (Note 5.)			0.5	V
los	Output Short Circuit Current	-130		-60	mA

NOTE: 100EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

5. All loading with 500 ohms to GND, CL = 20pF.

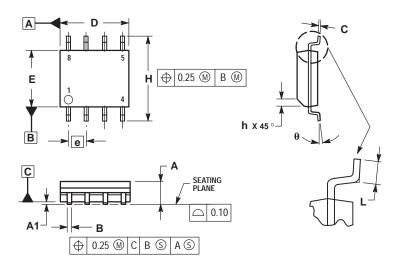
### AC CHARACTERISTICS (V $_{CC}$ = 3.3V $\pm$ 0.3V; GND = 0V)

		-40°C		25°C		85°C					
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f <sub>max</sub>	Maximum Toggle Frequency	275			275			275			MHz
tPLH, tPHL	Propagation Delay to Output Differential	800	1200	1800	800	1100	1600	800	1100	1600	ns
t <sub>SK++</sub> t <sub>SK</sub> t <sub>SKPP</sub>	Output-to-Output Skew++ Output-to-Output Skew Part-to-Part Skew (Note 6.)		60 25 500			60 25 500			60 25 500		ps
<sup>†</sup> JITTER	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
VPP	Input Voltage Swing (Differential) (Note 7.)	100	800	1200	100	800	1200	100	800	1200	mV
t <sub>r</sub>	Output Rise/Fall Times $Q, \overline{Q}$ (0.8V – 2.0V)	450 900	600 1160	750 1400	450 900	600 1100	750 1400	450 900	600 1100	750 1400	ps

<sup>6.</sup> Skews are measured between outputs under identical conditions.7. 200mV input guarantees full logic swing at the output.

#### **PACKAGE DIMENSIONS**

#### SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-06 ISSUE T

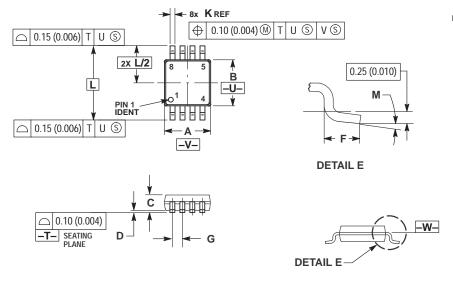


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. DIMENSIONS ARE IN MILLIMETER.
  3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
  5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS						
DIM	MIN	MAX					
Α	1.35	1.75					
A1	0.10	0.25					
В	0.35	0.49					
С	0.19	0.25					
D	4.80	5.00					
Ε	3.80	4.00					
е	1.27	BSC					
Н	5.80	6.20					
h	0.25	0.50					
L	0.40	1.25					
θ	0 °	7 º					

#### PACKAGE DIMENSIONS

#### TSSOP-8 **DT SUFFIX** PLASTIC TSSOP PACKAGE CASE 948R-02 ISSUE A



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED OLD (15 (6) 00A) DEP SIDE
  - FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

    4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

    5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

    6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIN	IETERS	INC	HES		
DIM	MIN MAX		MIN	MAX		
Α	2.90	3.10	0.114	0.122		
В	2.90	3.10	0.114	0.122		
С	0.80 1.10		0.031	0.043		
D	0.05	0.15	0.002	0.006		
F	0.40 0.70		0.016	0.028		
G	0.65	BSC	0.026 BS0			
K	K 0.25 0.40		0.010	0.016		
L		BSC	0.193	BSC		
M	0°	6°	0°	6°		

# **Notes**

# **Notes**

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